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FIG. 1A

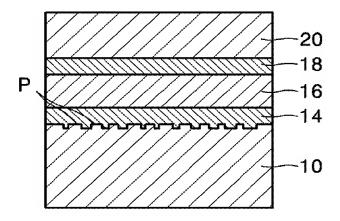


FIG. 1B

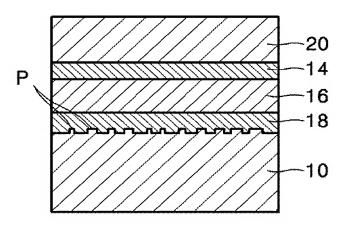
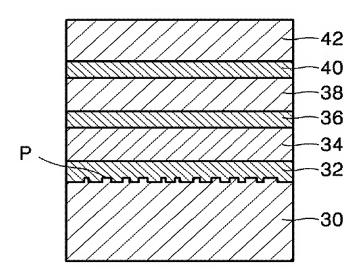


FIG. 2



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FIG. 3A

SUBSTRATE (1.1mm)

Ge-Sb-Te (33nm)

ZnS-SiO<sub>2</sub> (25nm)

PtOx (3.5nm)

ZnS-SiO<sub>2</sub> (50nm)

## FIG. 3B

SUBSTRATE (1.1mm)

ZnS-SiO<sub>2</sub> (25nm)

Ge-Sb-Te (33nm)

ZnS-SiO<sub>2</sub> (25nm)

PtOx (3.5nm)

ZnS-SiO<sub>2</sub> (50nm)

FIG. 4A

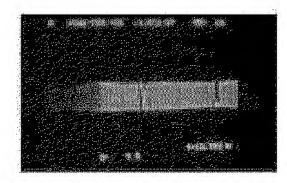


FIG. 4B

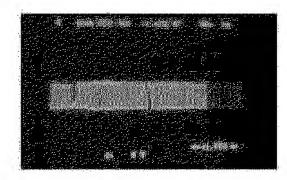


FIG. 4C

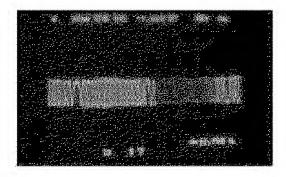


FIG. 4D

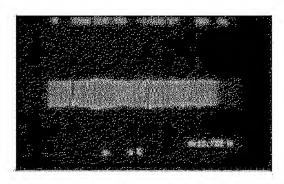


FIG. 4E

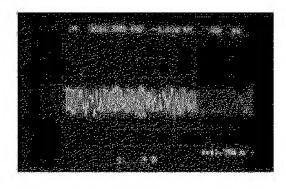
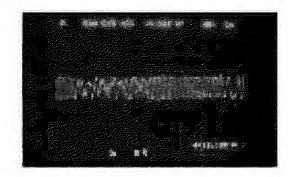


FIG. 5A



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FIG. 5B

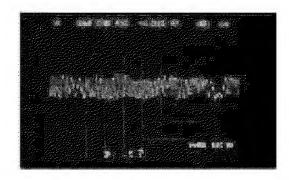


FIG. 5C

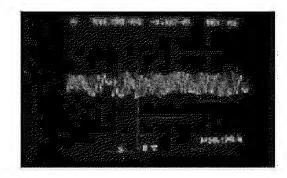


FIG. 5D

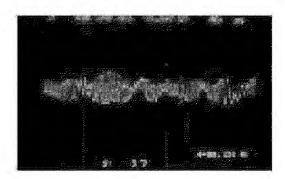
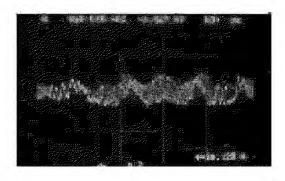


FIG. 5E



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FIG. 6

